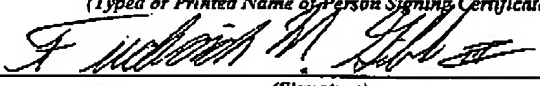


CERTIFICATE OF TRANSMISSION BY FACSIMILE (37 CFR 1.8)			Docket No. YO998426DIV
Applicant(s): Chan et al.			
Serial No. 10/051,562	Filing Date January 18, 2002	Examiner Novacek, Christy L.	Group Art Unit 2822
Invention: SELF-ALIGNED COUPLE-GATE MOSFET BY SELECTIVE EPITAXY AND SILICON WAFER BONDING TECHNIQUES			
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			FEB 03 2004 OFFICIAL
I hereby certify that this <u>Amendment Under 37 C.F.R. 1.111</u> (Identify type of correspondence)			
is being facsimile transmitted to the United States Patent and Trademark Office (Fax. No. <u>703-872-9306</u>)			
on <u>February 3, 2004</u> (Date)			
<div style="text-align: center;"><u>Frederick W. Gibb, III</u> (Typed or Printed Name of Person Signing Certificate)  (Signature)</div>			
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10/051,562

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re patent application of

Chan et al.

Serial No.: 10/051,562

Group Art Unit: 2822

Filed: January 18, 2002

Examiner: Novacek, Christy L.

**For: SELF-ALIGNED DOUBLE-GATE MOSFET BY SELECTIVE EPITAXY AND
SILICON WAFER BONDING TECHNIQUES.****OFFICIAL**Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450**AMENDMENT UNDER 37 C.F.R. §1.111**

Sir:

In response to the Office Action mailed November 4, 2003, please amend the
above-identified patent application as follows:**IN THE CLAIMS:**

Please amend the claims as follows.